Not Recommended for New Designs

This product was manufactured for Maxim by an outside wafer foundry using a process that is no longer available. It is not recommended for new designs. The data sheet remains available for existing users.

A Maxim replacement or an industry second-source may be available. Please see the QuickView data sheet for this part or contact technical support for assistance.

For further information, contact Maxim's Applications Tech Support.

Low-Noise, Precision Op Amp

General Description

The Maxim MXL1007 operational amplifier features lownoise, ±15V performance: 2.5nV/VHz wideband noise, 1/f corner frequency of 2Hz, and 60nVp-p 0.1Hz to 10Hz noise. Precision and speed performance includes 10µV typical offset voltage, 0.2µV/°C drift, 130dB CMRR and PSRR, and an 8MHz unity-gain stable bandwidth. In addition, the MXL1007's voltage gain is 20 million with a $2k\Omega$ load and 12 million with a 600Ω load.

Maxim's MXL1007 is a pin-compatible alternative to other industry-standard low-noise op amps such as the OP27 and LT1007.

For applications requiring higher performance, see the MAX427/MAX437 and MAX410/MAX412/MAX414 data sheets.

Applications

Low-Noise Signal Processing Threshold Detection Strain-Gauge Amplifiers Microphone Preamplifiers

Features

- Low-Noise Performance: 4.5nV/√Hz Max (10Hz) 3.8nV/√Hz Max (1kHz)
- High-Voltage Gain: 7 Million Min (2kΩ Load) 3 Million Min (600Ω Load)
- ♦ 25µV Max Offset Voltage
- ♦ 0.6µV/°C Max Drift
- 117dB Min CMRR

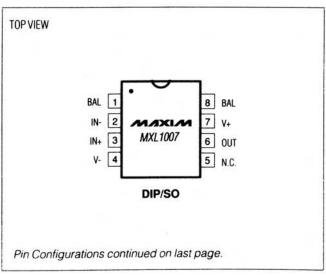
Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE	
MXL1007ACN8	0°C to +70°C	8 Plastic DIP	
MXL1007CN8	0°C to +70°C	8 Plastic DIP	
MXL1007CS8	0°C to +70°C	8 SO	
MXL1007CS	0°C to +70°C	16 Wide SO	
MXL1007AMJ8	-55°C to +125°C	8 CERDIP	
MXL1007MJ8	-55°C to +125°C	8 CERDIP	
MXL1007AMH	-55°C to +125°C	8 TO-99	
MXL1007MH	-55°C to +125°C	8 TO-99	

Typical Application Circuit

LOW-NOISE MICROPHONE PREAMPLIFIER 316k 5μF 100Ω w LOW-IMPEDANCE 1k MICROPHONE Ro ≟ 30k MIXLM 10k OUTPUT MXL1007 $(Z = 50\Omega TO 200\Omega)$ R2 1k $\frac{R3}{R1} \approx \frac{R4}{R2}$ 316k

Pin Configurations



MIXIM

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

Supply Voltage±22	٧
nput Voltage (Note 1)±22	V
Output Short-Circuit DurationContinuou	ıs
Differential Input Voltage (Note 2)±0.7	٧
Differential Input Current (Note 2)±25m.	A
Continuous Power Dissipation (T _A = +70°C)	
8-Pin Plastic DIP (derate 9.09mW/°C above +70°C)727mV	W
8-Pin SO (derate 5.88mW/°C above +70°C)471mV	W
16-Pin Wide SO (derate 9.52mW/°C above +70°C)726m\	W

8-Pin CERDIP (derate 8.00mW/°C abov	ve +70°C)640mW
8-Pin TO-99 (derate 6.67mW/°C above	
Operating Temperature Ranges:	
MXL1007AC/C	0°C to +70°C
MXL1007AM/M	55°C to +125°C
Junction Temperature Range	65°C to +150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10sec)	+300°C

Note 1: For supply voltages less than ±22V, the absolute maximum input voltage is equal to the supply voltage.

Note 2: MXL1007 inputs are protected by back-to-back diodes. Current-limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds ±0.7V, the input current should be limited to 25mA.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $(V_S = \pm 15V, T_A = +25^{\circ}C, unless otherwise noted.)$

PARAMETER	SYMBOL	CONDITIONS	MXL1007AM/AC			MXL1007M/C			
			MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage (Note 3)	Vos			10	25		20	60	μV
Long-Term Vos Stability (Notes 4, 5)	Vos/TIME			0.2	1.0		0.2	1.0	μV/Mo
Input Bias Current	IB			±10	±35		±15	±55	nA
Input Offset Current	los			7	30		12	50	nA
Input Voltage Range	Ivr		±11.0	±12.5		±11.0	±12.5		V
Input Resistance – Common Mode	RINCM			7			5		GΩ
Input Noise Voltage (Notes 5, 6)	e _{np-p}	0.1Hz to 10Hz		0.06	0.13		0.06	0.13	μV _{p-p}
Input Noise-Voltage Density (Note 5)	en	$f_0 = 10Hz$		2.8	4.5		2.8	4.5	nV∕√Hz
		$f_0 = 1kHz$		2.5	3.8		2.5	3.8	
Input Noise-Current Density (Notes 5, 7)	in	$f_0 = 10Hz$		1.5	4.0		1.5	4.0	pA/√Hz
		$f_0 = 1kHz$		0.4	0.6		0.4	0.6	
	Avo	$R_L \ge 2k\Omega$, $V_O = \pm 12V$	7.0	20.0		5.0	20.0		V/µV
Large-Signal Voltage Gain		$R_L \ge 1k\Omega$, $V_O = \pm 10V$	5.0	16.0		3.5	16.0		
		$R_L \ge 600\Omega$, $V_O = \pm 10V$	3.0	12.0		2.0	12.0		
Output Voltage Swing	Ma	$R_L \ge 2k\Omega$	±13.0	±13.8		±12.5	±13.5		V
Output voltage Swing	Vo	$R_L \geq 600\Omega$	±11.0	±12.5		±10.5	±10.5 ±12.5		
Open-Loop Output Resistance	Ro	$V_0 = 0$, $I_0 = 0$		70			70		Ω
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 11V$	117	130		110	126		dB
Power-Supply Rejection Ratio	PSRR	$V_S = \pm 4V$ to $\pm 18V$	110	130		106	126		dB
Gain-Bandwidth Product (Note 5)	GBP	$f_0 = 100kHz$	5.0	8.0		5.0	8.0		MHz
Slew Rate (Note 5)	SR	$R_L \ge 2k\Omega$	1.7	2.5		1.7	2.5		V/µs
Power Dissipation	PD	Vo = 0		80	120		80	140	mW

ELECTRICAL CHARACTERISTICS

 $(V_S = \pm 15V, T_A = -55^{\circ}C \text{ to } + 125^{\circ}C, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS	MX	M	UNITS				
			MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage (Note 3)	Vos			25	60		50	160	μV
Average Offset-Voltage Drift (Note 8)	TCVos	b		0.2	0.6		0.3	1.0	μV/°C
Input Offset Current	los			15	50		20	85	nA
Input Bias Current	IB			±20	±60		±35	±95	nA
Input Voltage Range	Ivr		±10.3	±11.5		±10.3	±11.5		٧
Common-Mode Rejection Ratio	CMRR	$V_{CM} = \pm 10.3V$	112	126		104	120		dB
Power-Supply Rejection Ratio	PSRR	$V_S = \pm 4.5 V \text{ to } \pm 18 V$	104	126		100	120		dB
Large-Signal Voltage Gain	Avol	$R_L \ge 2k\Omega$, $V_O = \pm 10V$	3.0	14.0		2.0	14.0		V/μV
		$R_L \ge 1k\Omega$, $V_O = \pm 10V$	2.0	10.0		1.5	10.0		
Maximum Output-Voltage Swing	Vout	$R_L \ge 2k\Omega$	±12.5	±13.5		±12.0	±13.5		٧
Power Dissipation	PD	Vo = 0		100	150		100	170	mW

ELECTRICAL CHARACTERISTICS

 $(V_S = \pm 15V, T_A = 0^{\circ}C \text{ to } +70^{\circ}C, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS	MXL1007AC			MXL1007C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	UNITS
Input Offset Voltage (Note 3)	Vos			20	50		35	110	μV
Average Offset-Voltage Drift (Note 8)	TCVos			0.2	0.6		0.3	1.0	μV/°C
Input Offset Current	los			10	40		15	70	nA
Input Bias Current	IB			±14	±45		±20	±75	nA
Input Voltage Range	Iva		±10.5	±11.8		±10.5	±11.8		V
Common-Mode Rejection Ratio	CMRR	V _{CM} = ±10.5V	114	126		106	120		dB
Power-Supply Rejection Ratio	PSRR	$V_S = \pm 4.5 V \text{ to } \pm 18 V$	106	126		102	120		dB
Large-Signal Voltage Gain	Avol	$R_L \ge 2k\Omega$, $V_O = \pm 10V$	4.0	18.0		2.5	18.0		V/μV
		$R_L \ge 1k\Omega$, $V_O = \pm 10V$	2.5	14.0		2.0	14.0		
Maximum Output-Voltage Swing	Vout	$R_L \ge 2k\Omega$	±12.5	±13.6		±12.0	±13.6		٧
Power Dissipation	PD	Vo = 0		90	144		90	160	mW

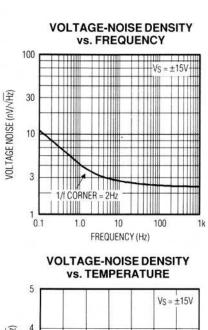
Note 3: Input Offset Voltage measurements are performed by automatic test equipment approximately 0.5 sec after application

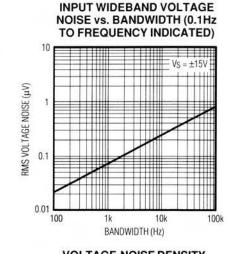
Note 4: Long-Term Input Offset Voltage Stability refers to the average trend line of Offset Voltage vs. Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in Vos during the first 30 days are typically

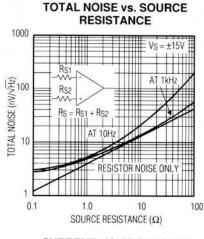
Note 5: This parameter is guaranteed by design and is not tested. Note 6: See the test circuit for 0.1Hz to 10Hz tester in the *Typical Operating Characteristics* section. Note 7: See the test circuit for current noise meaurement in the *Applications Information* section. Note 8: The Average Input Offset Drift performance is within the specificaions unnulled or when nulled with a pot having a range of $8k\Omega$ to $20k\Omega$. AM and AC grades are sample tested to 0.1% AQL. C grade is guaranteed by design.

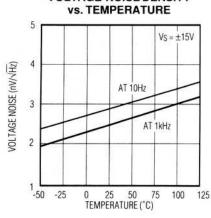
Typical Operating Characteristics

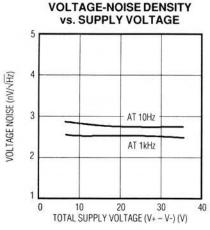
(TA = +25°C, unless otherwise noted)

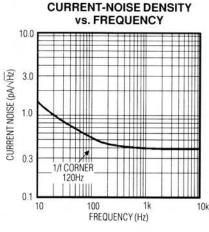


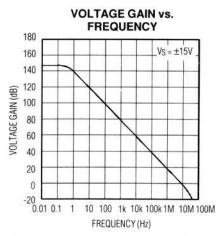


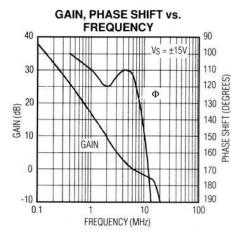


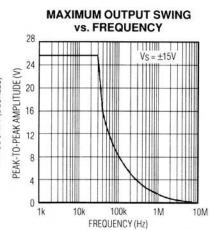








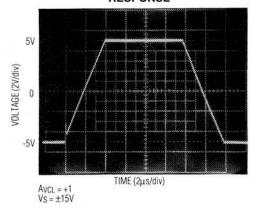




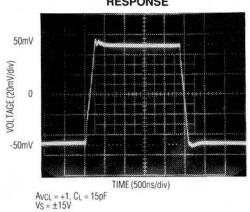
Typical Operating Characteristics (continued)

MAXIMUM OUTPUT VOLTAGE vs. LOAD RESISTANCE 15 12 POSITIVE SWING NEGATIVE SWING NEGATIVE SWING 100 300 1k 3k 10k LOAD RESISTANCE (Ω)

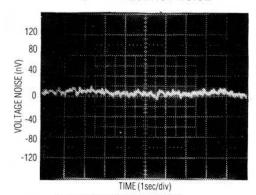
LARGE-SIGNAL TRANSIENT RESPONSE



SMALL-SIGNAL TRANSIENT RESPONSE



LOW-FREQUENCY NOISE



0.1Hz TO 10Hz PEAK-TO-PEAK NOISE

NOTE: (OSERVATION TIME LIMITED TO 10 SECONDS.)

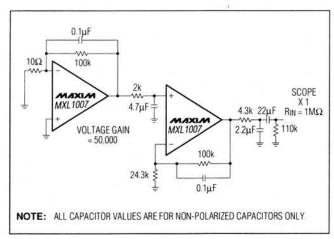


Figure 1. Voltage-Noise Test Circuit (0.1Hz to 10Hz)

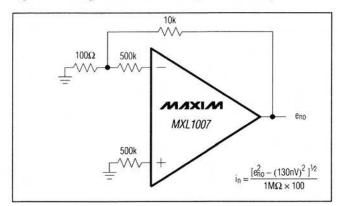


Figure 2. Current-Noise Test Circuit

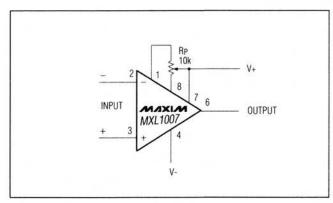
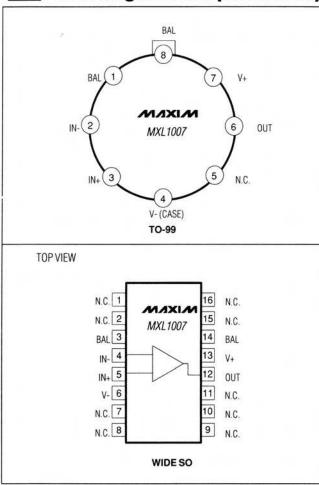


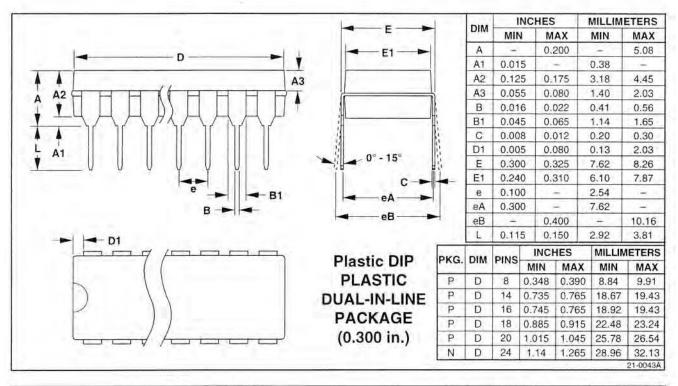
Figure 3. Offset Nulling Circuit

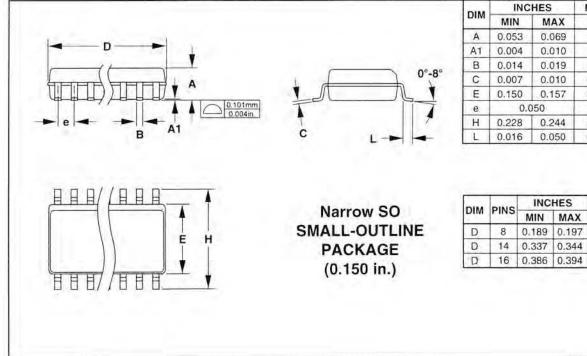
_Pin Configurations (continued)



Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)





MILLIMETERS

1.27

MILLIMETERS

MIN

4.80

8.55

9.80

MAX

1.75

0.25

0.49

0.25

4.00

6.20

1.27

MAX

5.00

8.75

10.00

21-0041A

MIN

1.35

0.10

0.35

0.19

3.80

5.80

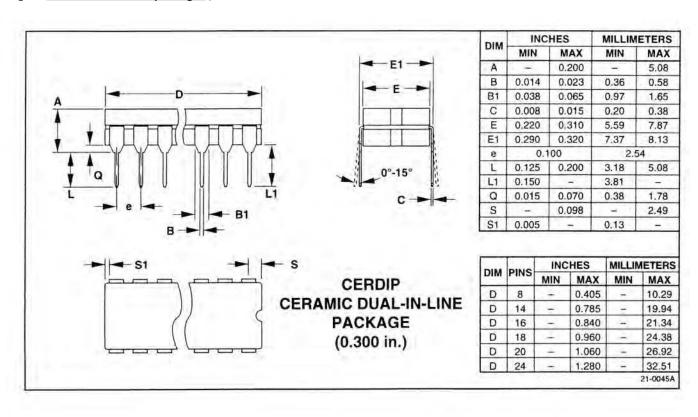
0.40

MAX

0.197

0.344

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)



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